HALOGEN FREE

GREEN



Vishay Semiconductors

High Speed Infrared Emitting Diode, 940 nm, GaAlAs, MQW



DESCRIPTION

VSMB10940 is an infrared, 940 nm side looking emitting diode in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed, molded in clear, untinted plastic package (with lens) for surface mounting (SMD).

FEATURES

Package type: Surface mount

Package form: Side view

• Dimensions (L x W x H in mm): 3 x 2 x 1

Peak wavelength: λ_p = 940 nm

High reliability

• High radiant power

High radiant intensity

· High speed

• Angle of half sensitivity: $\phi = \pm 75^{\circ}$

Low forward voltage

Package matches with detector VEMD10940F

• Floor life: 168 h, MSL 3, acc. J-STD-020

• Lead (Pb)-free reflow soldering

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- IR touch panel
- High power emitter for low space applications
- High performance transmissive or reflective sensors

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr), 20 mA	φ (deg)	λ _p (nm)	t _r (ns)	
VSMB10940	1	± 75	940	15	

Note

Test conditions see table "Basic Characteristics"

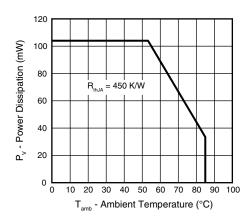
ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMB10940	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	side view		

Note

· MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	65	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	130	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	500	mA	
Power dissipation		P _V	104	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	according to fig. 9, J-STD-020	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	450	K/W	







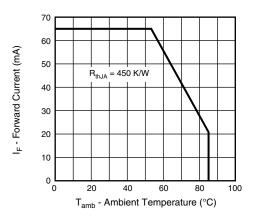


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	V _F	1.1	1.3	1.5	V
Forward voltage	$I_F = 65 \text{ mA}, t_p = 20 \text{ ms}$	V_{F}		1.35		V
	$I_F = 500 \text{ mA}, t_p = 100 \mu \text{s}$	V _F		1.8		V
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		- 1.5		mV/K
Reverse current	V _R = 5 V	I _R			10	μΑ
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $E = 0 \text{ mW/cm}^2$	CJ		21		pF
	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	l _e	0.5	1	1.5	mW/sr
Radiant intensity	$I_F = 65 \text{ mA}, t_p = 20 \text{ ms}$	l _e		3.05		mW/sr
	$I_F = 500 \text{ mA}, t_p = 100 \mu \text{s}$	l _e		13		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе		35		mW
Temperature coefficient of radiant power	I _F = 100 mA	TKφ _e		- 0.47		%/K
Angle of half intensity - horizontal		Φh		± 77.5		deg
Angle of half intensity - vertical		ϕ_{V}		± 72.5		deg
Peak wavelength	I _F = 30 mA	λ_{p}		940		nm
Spectral bandwidth	I _F = 30 mA	Δλ		25		nm
Temperature coefficient of λ _p	I _F = 30 mA	TK_{\lambdap}		0.3		nm
Rise time	I _F = 100 mA, 20 % to 80 %	t _r		15		ns
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		15		ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

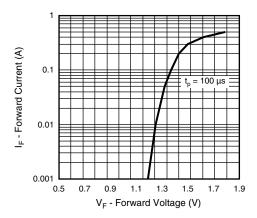


Fig. 3 - Forward Current vs. Forward Voltage

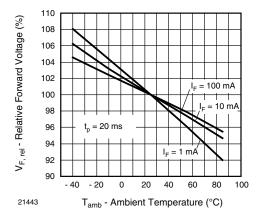


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

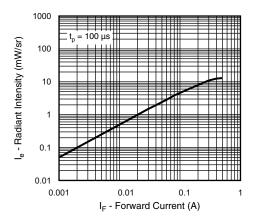


Fig. 5 - Radiant Intensity vs. Forward Current

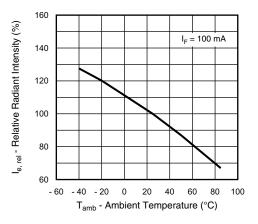


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

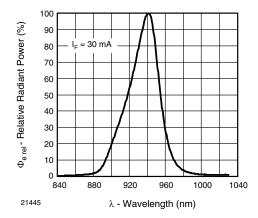


Fig. 7 - Relative Radiant Power vs. Wavelength

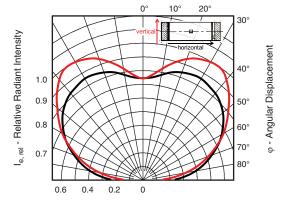


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

REFLOW SOLDER PROFILE

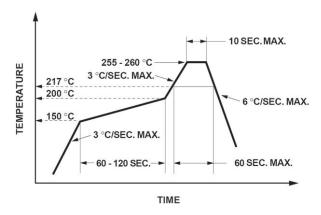


Fig. 9 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 3

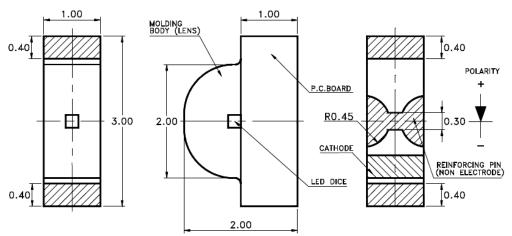
Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 60 %

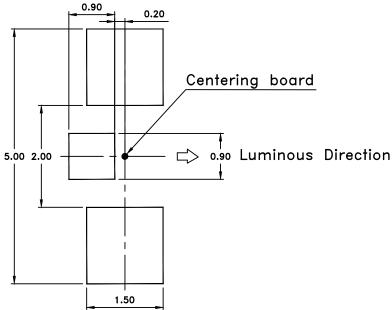
DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.

PACKAGE DIMENSIONS in millimeters

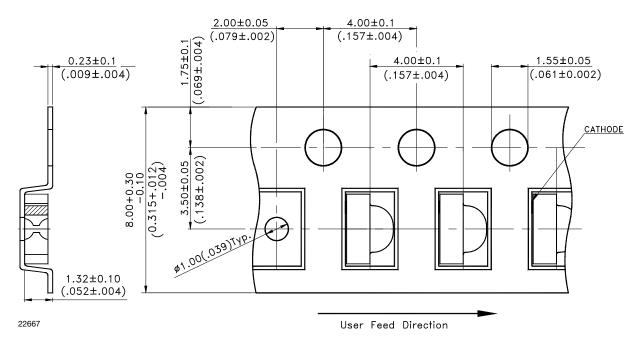


Recommended Solder Pad Footprint

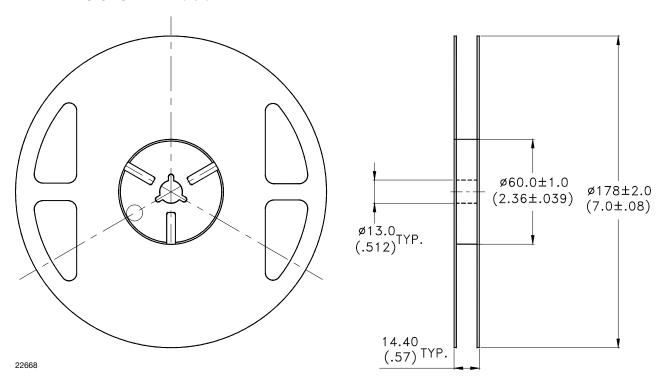




BLISTER TAPE DIMENSIONS in millimeters



REEL DIMENSIONS in millimeters





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